Vishay Semiconductors

High Performance Schottky Rectifier, 3 A



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DO-214AC (SMA)

PRODUCT SUMMARY					
Package	DO-214AC (SMA)				
I _{F(AV)}	3 A				
V _R	40 V				
V _F at I _F	0.46 V				
I _{RM}	20 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	6.0 mJ				

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Small footprint, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Switching power supplies
- Meter protection
- · Reverse protection for power input to PC board circuits
- · Battery isolation and charging
- · Low threshold voltage diode
- Freewheeling or by-pass diode
- · Low voltage clamp

DESCRIPTION

The VS-30MQ040HM3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	3	А			
V _{RRM}		40	V			
I _{FSM}	$t_p = 5 \ \mu s \ sine$	330	А			
V _F	2 A _{pk} , T _J = 125 °C	0.43	V			
TJ	Range	-40 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-30MQ040HM3	UNITS			
Maximum DC reverse voltage	V _R	40	V			
Maximum working peak reverse voltage	V _{RWM}	40	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDIT	IONS	VALUES	UNITS	
Maximum average forward current See fig. 4	$I_{F(AV)} \begin{cases} 50 \% \text{ duty cycle at } T_L = 89 \text{ °C}, \text{ rectangular waveform} \\ \text{On PC board } 9 \text{ mm}^2 \text{ island} \\ (0.013 \text{ mm thick copper pad area}) \end{cases}$		3	A		
Maximum peak one cycle			Following any rated load condition and with	330	•	
non-repetitive surge current See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	140	A	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А	

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(Pb) RoHS

COMPLIANT HALOGEN

UNITS

v



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VALUES

0.42 0.51

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS			
		1 A	T _{.1} = 25 °C			
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	3 A	1j=25 0			
	V FM (''	1 A	T.I = 125 °C			
		3 4	1j=125 C			

See fig. 1	- FIVI	1 A	T.I = 125 °C	0.34	-
		3 A	$1_{\rm J} = 125$ C	0.46	
Maximum reverse leakage current		T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA
See fig. 2	IRM	T _J = 125 °C	VR - naleu VR	20	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J}$ maximum		0.26	V
Forward slope resistance	r _t			64.6	mΩ
Typical junction capacitance	CT	V_R = 10 V_{DC} , T_J = 25 °C, test signal = 1 MHz		134	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approvimate weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (similar D-64)	3	F	

Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



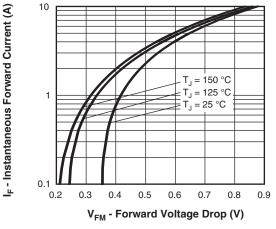
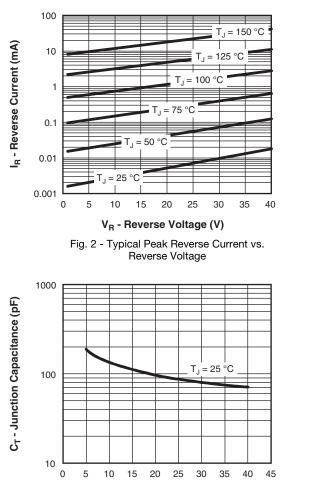
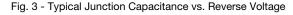


Fig. 1 - Maximum Forward Voltage Drop Characteristics

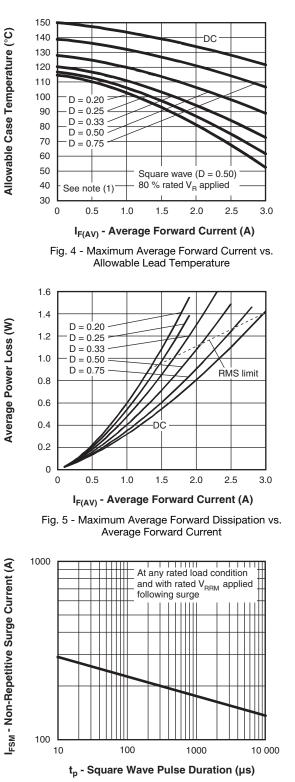


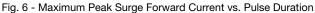
V_R - Reverse Voltage (V)



VS-30MQ040HM3

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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

Device code	VS-	30	м	Q	040	Н	М3
		2	3	4	5	6	7
	1	- Visl	nay Sem	niconduc	ctors pro	oduct	
	2	- Cur	rent rati	ng			
	3	- M =	SMA				
	4	- Q =	Schottk	ky "Q" se	eries		
	5	- Vol	tage rati	ng (040	= 40 V))	
	6	- H=	AEC-Q	101 qua	lified		
	7	- Env	vironmer	ntal digit	:		
		М3	= Halog	en-free,	RoHS-	complia	int and t

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-30MQ040HM3/5AT	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			



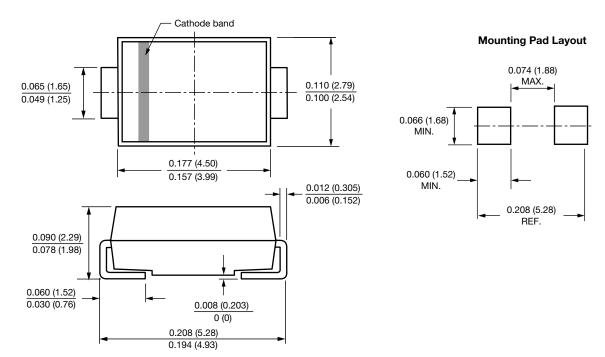
Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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